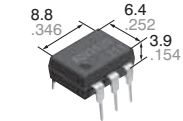
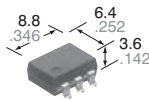


DIP6-pin type  
with high capacity  
of 2.5A load current

PhotoMOS®  
HE 1 Form A  
High Capacity

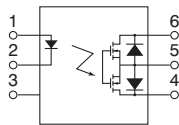


(Height includes  
standoff)



CAD Data

mm inch



## FEATURES

1. Greatly increased load current in a compact DIP package  
Continuous load current: 2.5A
2. Greatly improved specifications allow you to use this in place of mercury and mechanical relays.

## TYPICAL APPLICATIONS

- Security equipment
- Fire-preventing system
- Measuring instruments

## TYPES

	Output rating*		Package	Part No.				Packing quantity	
				Through hole terminal	Surface-mount terminal			Tube	Tape and reel
	Load voltage	Load current			Tube packing style		Tape and reel packing style		
				Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side				
AC/DC dual use	60 V	2.5 A	DIP6-pin	AQV252G	AQV252GA	AQV252GAX	AQV252GAZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.

\*Indicate the peak AC and DC values.

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the relay.

## RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

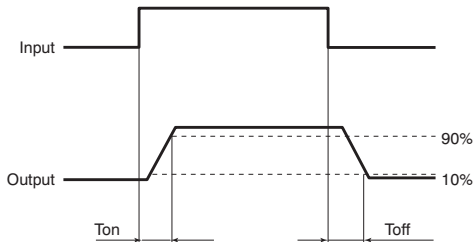
Item		Symbol	Type of connection	AQV252G(A)	Remarks
Input	LED forward current	$I_F$	A	50 mA	
	LED reverse voltage	$V_R$		5 V	
	Peak forward current	$I_{FP}$		1 A	$f = 100 \text{ Hz}$ , Duty factor = 0.1%
	Power dissipation	$P_{in}$		75 mW	
Load voltage (peak AC)		$V_L$		60 V	
Output	Continuous load current	$I_L$	B	2.5 A	A connection: Peak AC, DC B, C connection: DC
			C	3.5 A	
				5.0 A	
Peak load current		$I_{peak}$		6.0 A	100ms (1 shot), $V_L = \text{DC}$
Power dissipation		$P_{out}$		500 mW	
Total power dissipation		$P_T$		550 mW	
I/O isolation voltage		$V_{iso}$		1,500 V AC	
Temperature limits	Operating	$T_{opr}$		-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures
	Storage	$T_{stg}$		-40°C to +100°C -40°F to +212°F	

# HE 1 Form A High Capacity

## 2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV252G(A)	Condition
Input	LED operate current	Typical	I <sub>Fon</sub>	0.5 mA	I <sub>L</sub> = 100mA
		Maximum		3 mA	
	LED turn off current	Minimum	I <sub>Foff</sub>	0.2 mA	I <sub>L</sub> = 100mA
		Typical		0.45 mA	
LED dropout voltage	Typical	V <sub>F</sub>	1.14 V (1.32 V at I <sub>F</sub> = 50 mA)		I <sub>F</sub> = 5 mA
	Maximum		1.5 V		
Output	On resistance	Typical	R <sub>on</sub>	0.08 Ω	I <sub>F</sub> = 5 mA I <sub>L</sub> = Max. Within 1 s on time
		Maximum		0.12 Ω	
		Typical	R <sub>on</sub>	0.04 Ω	
		Maximum		0.06 Ω	
		Typical	R <sub>on</sub>	0.02 Ω	
		Maximum		0.03 Ω	
Off state leakage current	Maximum	I <sub>Leak</sub>	1 μA	I <sub>F</sub> = 0 mA, V <sub>L</sub> = Max.	
Transfer characteristics	Turn on time*	Typical	T <sub>on</sub>	1.1 ms	I <sub>F</sub> = 5 mA, I <sub>L</sub> = 100 mA V <sub>L</sub> = 10 V
		Maximum		5.0 ms	
	Turn off time*	Typical	T <sub>off</sub>	0.25 ms	I <sub>F</sub> = 5 mA, I <sub>L</sub> = 100 mA V <sub>L</sub> = 10 V
		Maximum		0.5 ms	
	I/O capacitance	Typical	C <sub>iso</sub>	0.8 pF	f = 1 MHz
Maximum		1.5 pF		V <sub>B</sub> = 0 V	
Initial I/O isolation resistance	Minimum	R <sub>iso</sub>	1,000 MΩ	500 V DC	

\*Turn on/Turn off time



## RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I <sub>F</sub>	5 to 10	mA

### ■ Dimensions

### ■ Schematic and Wiring Diagrams

### ■ Cautions for Use

■ These products are not designed for automotive use.

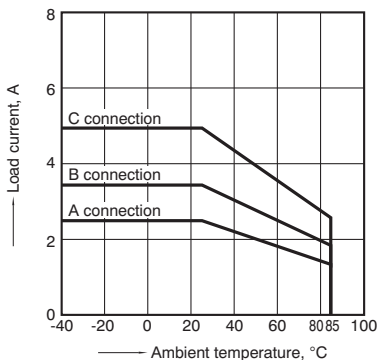
If you are considering to use these products for automotive applications, please contact your local Panasonic technical representative.

Please refer to our information on [PhotoMOS Relays for Automotive Applications](#).

## REFERENCE DATA

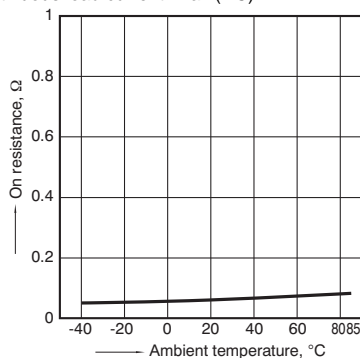
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C  
-40°F to +185°F



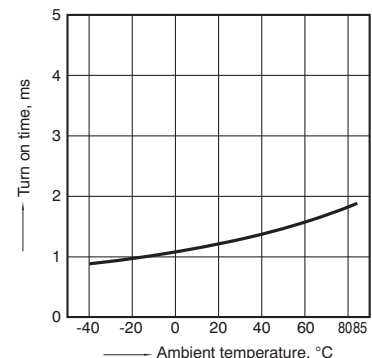
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;  
LED current: 5 mA; Load voltage: Max. (DC)  
Continuous load current: Max.(DC)



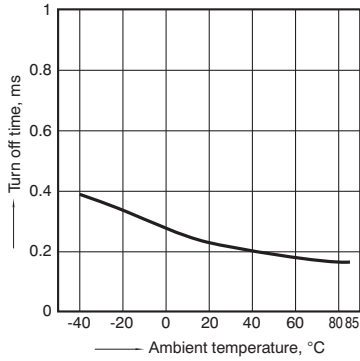
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC);  
Continuous load current: 100 mA (DC)



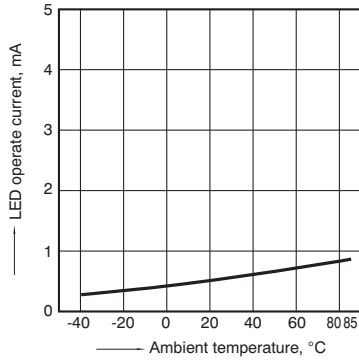
**4. Turn off time vs. ambient temperature characteristics**

LED current: 5 mA; Load voltage: 10 V (DC);  
Continuous load current: 100 mA (DC)



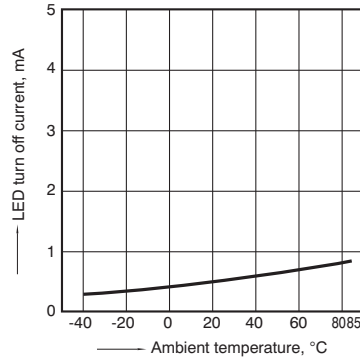
**5. LED operate current vs. ambient temperature characteristics**

Load voltage: 10 V (DC);  
Continuous load current: 100mA (DC)



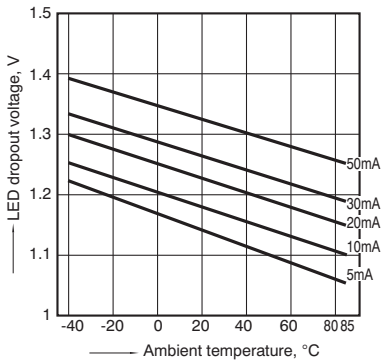
**6. LED turn off current vs. ambient temperature characteristics**

Load voltage: 10 V (DC);  
Continuous load current: 100mA (DC)



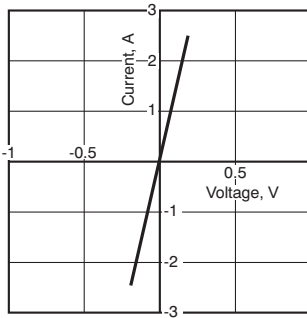
**7. LED dropout voltage vs. ambient temperature characteristics**

LED current: 5 to 50 mA



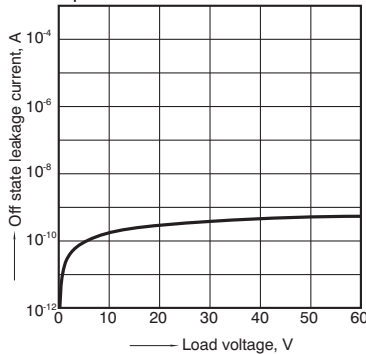
**8. Current vs. voltage characteristics of output at MOS portion**

Measured portion: between terminals 4 and 6;  
Ambient temperature: 25°C 77°F



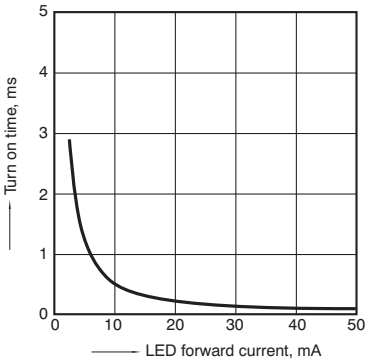
**9. Off state leakage current vs. load voltage characteristics**

Measured portion: between terminals 4 and 6;  
Ambient temperature: 25°C 77°F



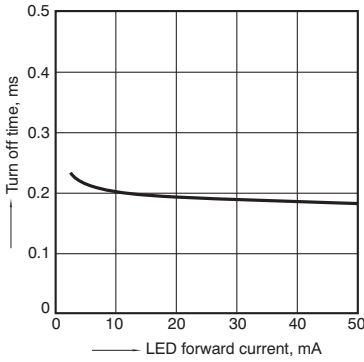
**10. Turn on time vs. LED forward current characteristics**

Measured portion: between terminals 4 and 6;  
Load voltage: 10 V (DC);  
Continuous load current: 100 mA (DC);  
Ambient temperature: 25°C 77°F



**11. Turn off time vs. LED forward current characteristics**

Measured portion: between terminals 4 and 6;  
Load voltage: 10 V (DC);  
Continuous load current: 100 mA (DC);  
Ambient temperature: 25°C 77°F



**12. Output capacitance vs. applied voltage characteristics**

Measured portion: between terminals 4 and 6;  
Frequency: 1 MHz;  
Ambient temperature: 25°C 77°F

